

MPSW56



PNP General Purpose Amplifier

This device is designed for general purpose medium power amplifiers and switches requiring collector currents to 800 mA. Sourced from Process 79.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	80	V
V _{CBO}	Collector-Base Voltage	80	V
V _{EBO}	Emitter-Base Voltage	4.0	V
I _C	Collector Current - Continuous	1.0	А
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		MPSW56	
P _D	Total Device Dissipation	1.0	W
	Derate above 25°C	8.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	50	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	125	°C/W

^{*}Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm².

PNP General Purpose Amplifier

Max

Min

(continued)

Units

Electrica	al Char	acter	istics

Parameter

Symbol

TA = 25°C unless otherwise noted

Test Conditions

V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	$I_C = 1.0 \text{ m A}, I_B = 0$	80		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 100 μA, I _E = 0	80		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1.0 m A, I _C = 0	4.0		V
Ісво	Collector-Cutoff Current	V _{CB} = 60 V, I _E = 0		0.1	μΑ
I _{CEO}	Collector-Cutoff Current	V _{CE} = 60 V		0.5	μΑ
I _{EBO}	Emitter-Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_{C} = 0$		0.10	μΑ

ON CHARACTERISTICS*

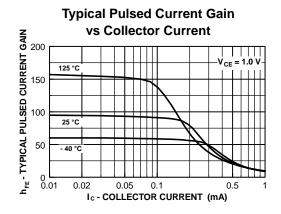
h _{FE}	DC Current Gain	$I_C = 50 \text{ mA}, V_{CE} = 1.0 \text{ V}$	100		
		$I_C = 250 \text{ mA}, V_{CE} = 1.0 \text{ V}$	50		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 250 \text{ mA}, I_B = 10 \text{ mA}$		0.5	V
V _{BE(on)}	Base-Emitter On Voltage	$I_C = 250 \text{ mA}, V_{CE} = 5.0 \text{ V}$		1.2	V

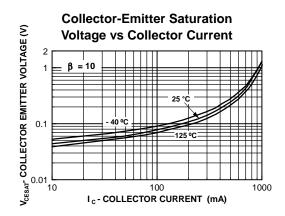
SMALL SIGNAL CHARACTERISTICS

f _T	Current Gain-Bandwidth Product	$I_C = 250 \text{ mA}, V_{CE} = 5.0 \text{ V},$ f = 20 MHz	50		MHz
Cob	Collector-Base Capacitance	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1.0 \text{ MHz}$		15	pF

^{*}Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 1.0%

Typical Characteristics

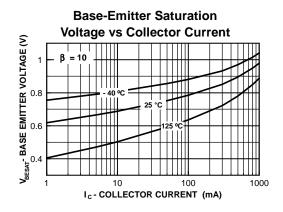


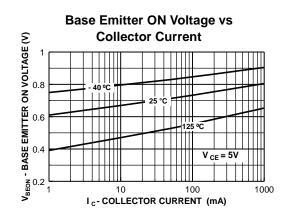


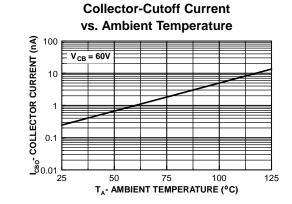
PNP General Purpose Amplifier

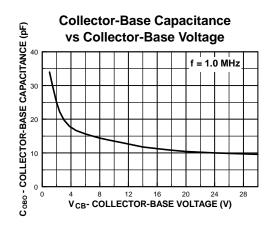
(continued)

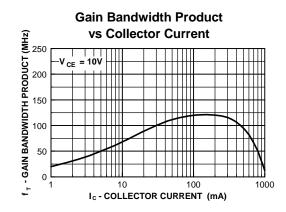
Typical Characteristics (continued)

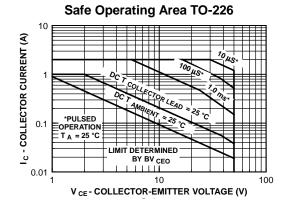






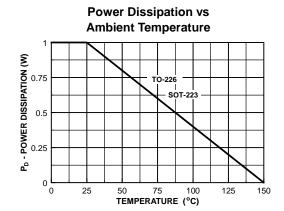


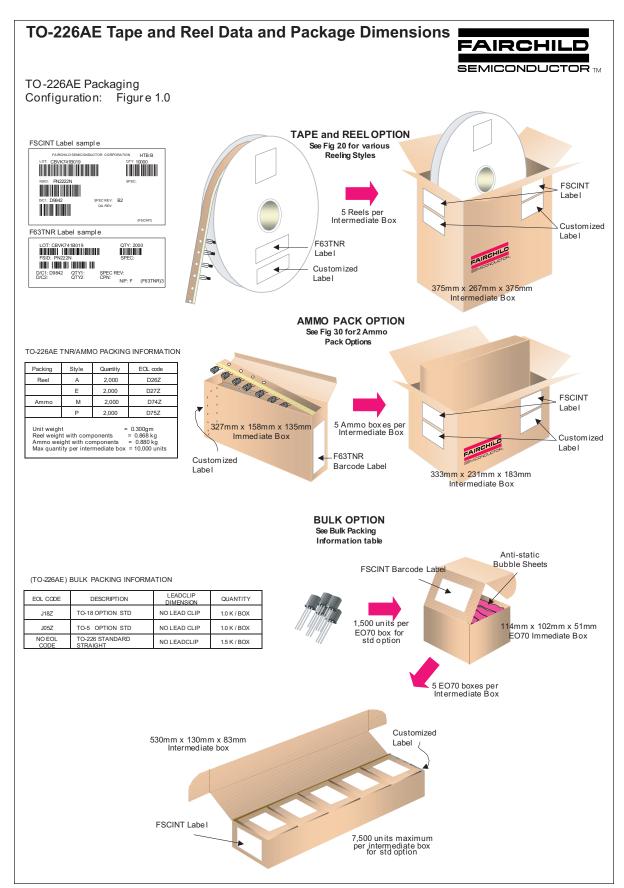




PNP General Purpose Amplifier (continued)

Typical Characteristics (continued)

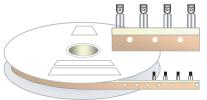




TO-226AE Tape and Reel Data and Package Dimensions, continued

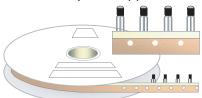
TO-226AE Reeling Style Configuration: Figure 2.0

Machine Option"A" (H)



Style "A", D26Z, D70Z (s/h)

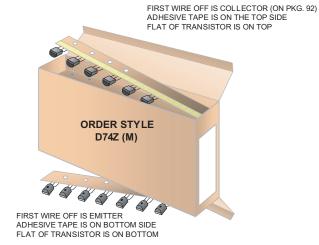
Machine Option"E" (J)



Style "E", D27Z, D71Z (s/h)

TO-226AE Radial Ammo Packaging

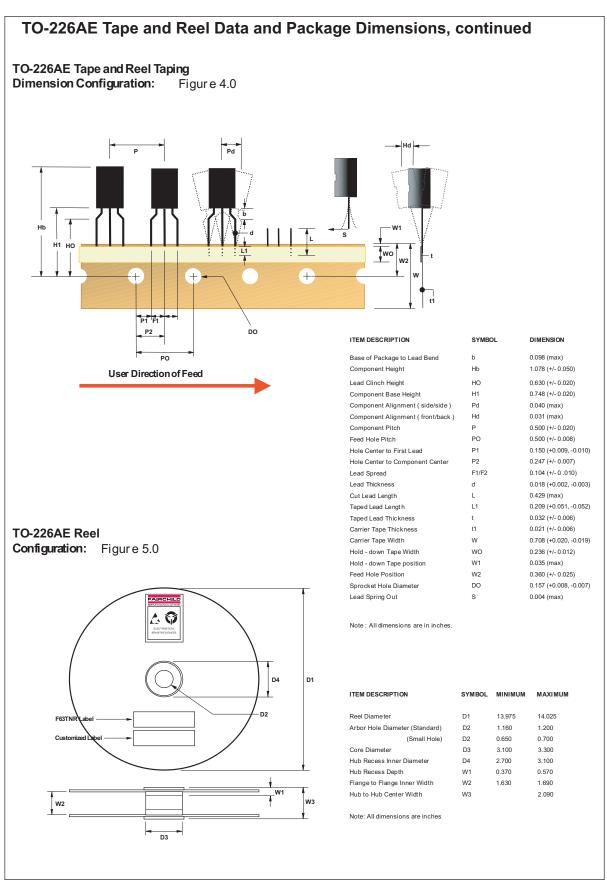
Configuration: Figure 3.0



FIRST WIRE OFF IS EMITTER (ON PKG. 92)
ADHESIVE TAPE IS ON THE TOP SIDE
FLAT OF TRANSISTOR IS ON BOTTOM

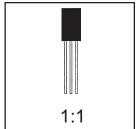
ORDER STYLE
D75Z (P)

FIRST WIRE OFF IS COLLECTOR ADHESIVE TAPE IS ON BOTTOM SIDE FLAT OF TRANSISTOR IS ON TOP



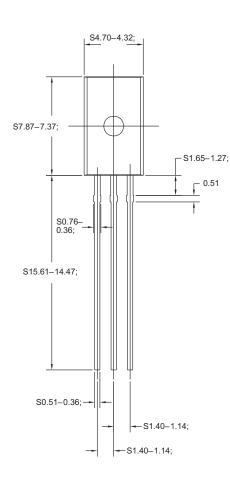
TO-226AE Tape and Reel Data and Package Dimensions, continued TO-226AE (FS PKG Code 95, 99)





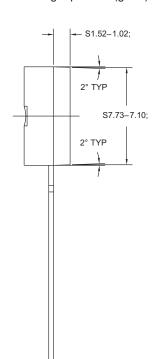
Scale 1:1 on letter size paper Dimensions shown below are in: inches [millimeters]

Part Weight per unit (gram): 0.300



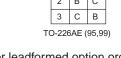
S4.45-3.81;

S2.41-2.13;





-S0.48-0.30;



For leadformed option ordering, refer to Tape & Reel data information.

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